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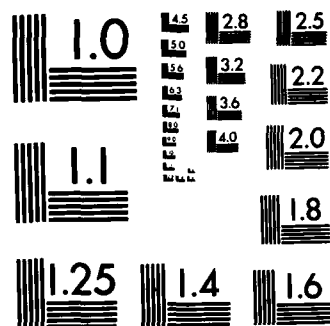
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CURE MONITORING AND CONTROL WITH
COMBINED DIELECTRIC/TEMPERATURE PROBES

By

Stephen D. Senturia, Norman F. Sheppard, Jr.,
Huan L. Lee, and Steven B. Marshall

Article prepared for presentation at
The 1983 SAMPE Meeting, Anaheim, CA, April 1983

MASSACHUSETTS INSTITUTE OF TECHNOLOGY
Department of Electrical Engineering and Computer Science
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This paper reports a new development in Microdielectrometry technology, the addition of a temperature sensor to the probe. The combined dielectric/temperature probe provides highly localized measurements of both temperature and changing dielectric properties. Data are presented that illustrate the use of the Microdielectrometer to detect the viscosity minimum during cure of staged prepreg resin, and the use of the on-chip temperature feature to provide feedback control signals during a test cure.



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CURE MONITORING AND CONTROL
WITH COMBINED DIELECTRIC/TEMPERATURE PROBES
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ABSTRACT

The dielectric and conductive properties of resins used as adhesives and as matrices in composites undergo large changes during cure. The use of these changing electrical properties to monitor cure is a well established technique. The most common structure for such measurements is a parallel plate capacitor using fixed metal plates or metal foils. A relatively new alternative structure is the "Microdielectrometer chip", a miniature integrated circuit probe that can be embedded in the sample under test. This paper reports a new development in Microdielectrometry technology, the addition of a temperature sensor to the probe. The combined dielectric/temperature probe provides highly localized measurements of both temperature and changing dielectric properties. Data are presented that illustrate the use of the Microdielectrometer to detect the vis-

cosity minimum during cure of staged prepreg resin, and the use of the on-chip temperature feature to provide feedback control signals during a test cure.

Keywords: Cure monitoring and control, dielectric sensor, temperature sensor.

1. INTRODUCTION

The large changes that occur in the dielectric and conductive properties of resins and structural adhesives during cure are well known. Several methods of monitoring cure based on these changing electrical properties have been reported. Ion graphing is a technique which monitors the dramatic drop in DC conductivity that occurs when a resin gels (1). This same conductivity change can be observed in conventional AC dielectric measurements at sufficiently low frequencies, using either parallel-plate capacitor geometries (2,3,4), or using integrated circuit Microdielec-

trometer probes (5,6). In addition to the conductivity changes, there are clearly observable changes in dielectric permittivity due to the increased hindrance to dipole rotation as resins vitrify. Associated with this effect is a peak in the dielectric loss factor.

Temperature plays a key role in dielectric cure monitoring, and not simply because of the obvious temperature dependence of all reaction rates. The low-frequency conductivity of resins and the relaxation times associated with dipole rotation are intrinsically temperature dependent as well as dependent on the state of cure. Therefore, proper interpretation of dielectric cure data requires knowledge of the temperature. In large parts, temperature gradients set up by the exothermic cure reaction can modify reaction rates and can also modify dielectric properties. It would be desirable, therefore, to be able to make temperature measurements at the same point in the resin from which dielectric signals are being obtained. This paper reports a new Microdielectrometer chip which incorporates an elementary temperature sensor, thereby permitting highly localized combined dielectric/temperature measurements from a single probe.

2. BACKGROUND

2.1 Measurement of Dielectric Properties

In a parallel-plate geometry, the pair of plates form a circuit element which can be represented as a capacitor in parallel with a conductor. The capacitance of the capacitor depends on the area of the plates, the spacing between the plates, and on the dielectric permittivity ϵ' of the medium between the plates. The conductance of the conductor in parallel with the capacitor depends similarly on the plate area and spacing, and also depends on the conductivity of the medium σ . A conventional way of relating the permittivity and conductivity contributions to one another is to define a quantity with the same dimensions as ϵ' , but proportional to conductivity. From basic electromagnetic theory, the correct corresponding quantity, called the loss factor and denoted by ϵ'' , is equal to σ/ω , where ω is the angular frequency at which both ϵ' and ϵ'' are measured. Both ϵ' and ϵ'' are usually reported in units of the permittivity of free space, ϵ_0 , which has the value 8.85×10^{-14} Farads/cm. In this case, the ϵ' value corresponds to the conventionally defined dielectric constant, and a material with an ϵ'' value of unity at a frequency of 1 Hz has a conductivity equal to 5.56×10^{-13} (Ohm cm)⁻¹.

Because both the capacitance and conductance measured from parallel plates depend directly on plate spacing, and because this spacing typically changes during a cure cycle either by shrinkage of the curing material or through the application of pressure, one usually finds reports of the ratio of ϵ'' to ϵ' , called the loss tangent (or, conventionally, $\tan\delta$). An equivalent quantity is the dissipation factor of the capacitor, often denoted by D. The benefit in working with $\tan\delta$ is that it is independent of plate spacing, at least to first order. The disadvantage of working with $\tan\delta$ is that when one observes a change, one does not know whether to attribute that change to ϵ' or to ϵ'' , or to both. Because the conductivity contributes directly to ϵ'' , and can also introduce artifacts in ϵ' early in cure (see below), it is highly desirable to separate ϵ' from ϵ'' . The accuracy of this separation with parallel plates depends on knowing and stabilizing the plate area and spacing.

The Microdielectrometry approach to dielectric measurements was first reported at the 1981 SAMPE meeting (5). A miniature integrated circuit (2x4 mm in the new design) contains a pair of interdigitated electrodes, one of which is driven with the AC signal, the other of which serves to collect

charge. On-chip amplifiers and off-chip electronic circuitry permit the equivalent of 0.1 pF capacitors to be measured at frequencies as low as 1 Hz with good signal to noise ratio. Because the electrodes are rigid, and are manufactured with microelectronic precision, the intrinsic calibration of the sensor is stable with respect both to temperature and pressure variations. Thus, with the Microdielectrometer, direct separation of ϵ' from ϵ'' is always possible. There is no need to combine the measured quantities into $\tan\delta$ to cancel out electrode spacing variations.

Both parallel plate and microdielectrometer structures measure the same basic quantities, ϵ' and ϵ'' , which can be expressed as

$$\epsilon' = \epsilon_{\infty} + \epsilon'_{\text{dipole}} \quad (2.1)$$

$$\epsilon'' = \frac{\sigma}{\omega} + \epsilon''_{\text{dipole}} \quad (2.2)$$

where ϵ_{∞} is the high frequency dielectric permittivity, σ is the conductivity and ω is the angular frequency. The last term in each expression is the contribution of dipole orientation to the dielectric properties. For dipoles having a single relaxation time τ , Debye (7) proposed that these should be

$$\epsilon'_{\text{dipole}} = \frac{(\epsilon_0 - \epsilon_{\infty})}{1 + (\omega\tau)^2} \quad (2.3)$$

$$\epsilon''_{\text{dipole}} = \frac{(\epsilon_0 - \epsilon_{\infty})\omega\tau}{1 + (\omega\tau)^2} \quad (2.4)$$

where ϵ_0 is the low frequency dielectric permittivity. Note that for $\omega\tau=1$, $\epsilon'_{\text{dipole}}$ is half of $(\epsilon_0 - \epsilon_\infty)$ and $\epsilon''_{\text{dipole}}$ attains its maximum value. In the calculations below a modified form of the Debye equations, proposed by Cole and Cole (8), are used. The modified expressions include an additional parameter, β , which accounts for the distribution of relaxation times in real materials.

In order to provide some insight into what these equations mean, Figure 1 shows a plot of the variation of ϵ' and of $\log \epsilon''$ versus isothermal cure time at four fre-

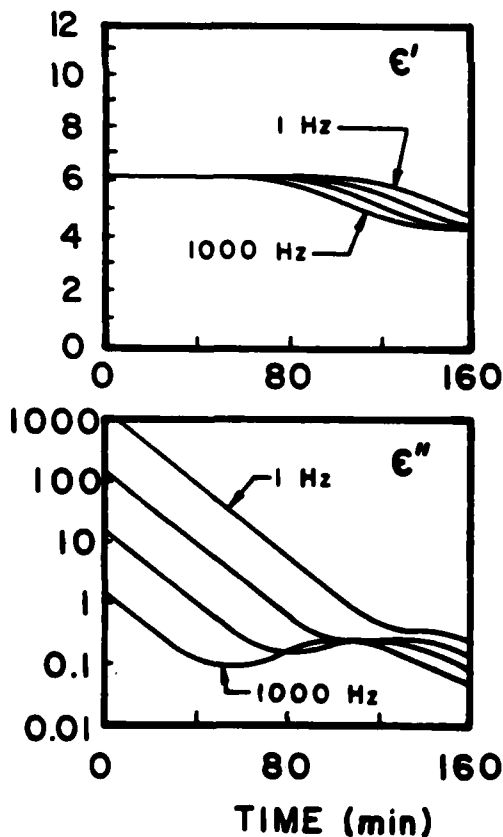


Fig. 1 ϵ' and ϵ'' versus time for the model of Eqs. 2.1 and 2.2, with parameters to match Fig. 2 data. Frequencies are 1,10,100 and 1000 Hz

quencies for an idealized material in which the conductivity is assumed to decay exponentially with time (due to cross linking), and the dipole relaxation time is assumed to increase exponentially with time. Numerical values typical of the cure of DGEBA with menthane diamine at 90°C were used to make the plots (the actual data are discussed in the following paragraph). Note the classical dipole relaxation in ϵ' , occurring later in time at successively lower frequencies because of the increase in τ with cure time. Note also that early in cure, the ϵ'' at each frequency decays exponenti-

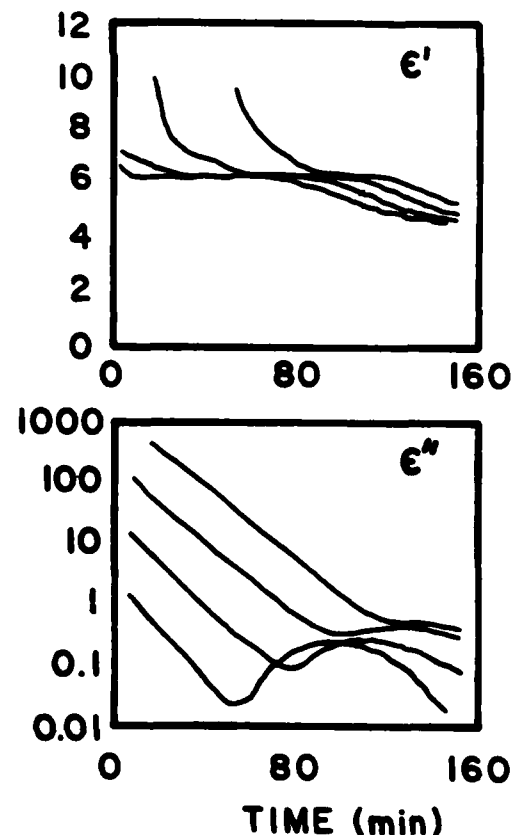


Fig. 2 ϵ' and ϵ'' versus time for DGEBA cured with menthane diamine at 90°C.

ally with time (following the conductivity contribution), and that the ϵ'' value at any time appears to be equal to a constant divided by frequency (that is, an increase in frequency by a factor of 10 produces a corresponding drop in ϵ'' by a factor of 10). This frequency dependence assures that the effect being observed is a conductivity rather than a dipole loss. Note, however, that later in cure, loss peaks due to the dipole orientation are observed, particularly at higher frequencies.

Experimental behavior is very similar to this ideal model. Figure 2 shows plots corresponding to the model curves of Fig. 1 for DGEBA cured with menthane diamine at 90°C. The overall resemblance is immediately noticeable. Two differences are evident, however. Early in cure, the experimental ϵ' value is much larger than ϵ_0 , which has a value of 6.5 in this example. The reason for this is believed to be that the electrodes are blocking, and that the ions that give rise to the bulk conductivity accumulate at the electrodes. This effect is well known in electrolytes (9). From an experimental point of view, we usually observe very large ϵ' in the presence of large ϵ'' . A second difference between the model and experiment is that late in cure, the changes in properties appear

to slow down and cease. This is consistent with a decrease in reaction rate after vitrification, which was not included in the simple illustrative model.

From the above example, it is clear that by observing ϵ'' at several different frequencies, one can identify whether one is observing a conductivity or a dipole loss. An important additional fact is that this conductivity is well correlated with the viscosity of the medium (6,10). Thus, when curing a prepreg, one should expect a peak in ϵ'' corresponding to the viscosity minimum. An example of such a result is presented in Section 3.1 below.

2.2 Temperature Measurement with Diodes

Semiconductor diodes have current-voltage characteristics with a sufficiently stable and predictable temperature dependence to permit their use as thermometers. If the diode carries a forward current that is large enough to mask surface and space-charge recombination effects, and at the same time small enough to avoid high-level injection phenomena, then at a fixed current the variation of forward biased voltage with temperature is derivable from basic theory, and equals $-2.3 \text{ mV}/^\circ\text{C}$. Ideally, one need only calibrate the forward voltage at one temperature, such as room

temperature, but in practice, parasitic effects may lead to small departures from the theoretical temperature dependence.

Because the Microdielectrometer probe is an integrated circuit, a temperature sensor diode can be incorporated in the probe itself, using the same fabrication procedure. The photomicrograph of Figure 3 shows the top view of the present sensor. Of particular interest are the interdigitated electrodes used to measure dielectric properties, and the added diode used to measure temperature. The substrate on which these devices are fabricated is silicon, and is a good thermal conductor. Therefore, the diode and electrode temperatures cannot be significantly different. The center-to-center distance between the diode and the electrode array is only 0.04 mm.

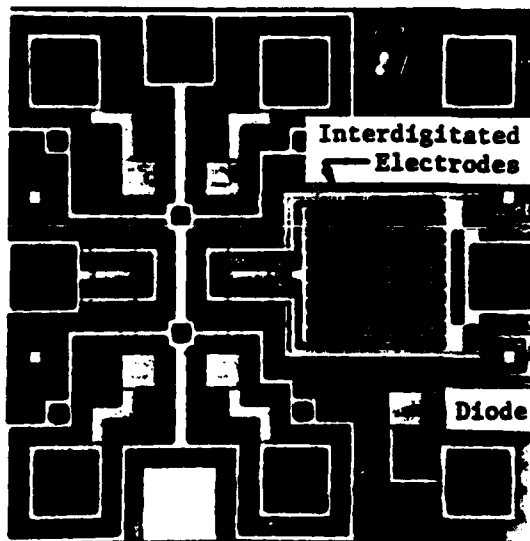


Fig. 3 Microdielectrometer

Figure 4 shows a calibration curve for two different diodes, one uncoated and one coated with cured DGEBA/MPDA resin. The voltage variation is plotted relative to the forward voltage at 20°C. The forward current is fixed at 100 microamps. A least-squares best fit line was calculated from the data for each diode, and in both cases the slope was $-2.26 \text{ mV}/^\circ\text{C}$, indicating ideal behavior. Our usual procedure is to measure the forward voltage at room temperature prior to a cure experiment, and then to use the $2.26 \text{ mV}/^\circ\text{C}$ slope to determine the temperature from the diode forward voltage. Over the range 20°C to 180°C, this yields results that should be accurate to better than 2°C. The incremental sensitivity of the temperature sensor is 0.2°C. For absolute accuracy in the 0.2°C range, a more complete calibration would be required.

3. EXPERIMENTAL RESULTS

3.1 Cure of Staged Prepreg Resin

As an illustration of the use of the combined dielectric/temperature probe in the present version of the Microdielectrometer chip, a ramped cure of a staged prepreg resin was carried out. Samples of epoxy-glass prepreg were obtained from a circuit-board laminate manufacturer. The basic formulation is a brominated epoxy resin cured with DICY. The prepreg cloth had been coated and staged. Several sheets of the cloth were

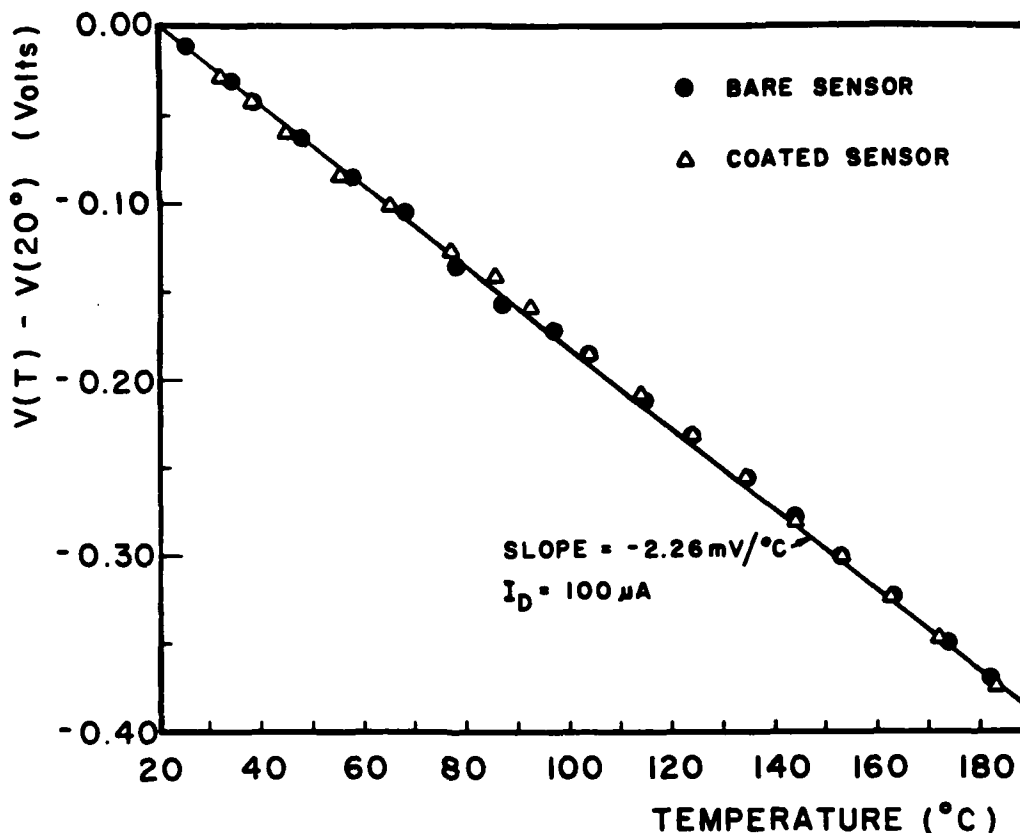


Fig. 4 Diode forward voltage versus temperature at fixed current of 100 μA for both uncoated and resin-coated devices.

crumbled to collect the resin, which at this point was in the form of a coarse powder. Some of the powder was placed directly on the surface of a Microdi-electrometer chip. The probe was placed in an oven and the temperature was ramped at a rate of 2°C per minute from 70°C to 170°C, then held. Signals were obtained as soon as the resin began to melt and flow onto the chip surface. Figure 5 shows a plot of temperature and loss factor versus time. The frequency dependence of the loss factor corresponds to conductivity rather than dipole orientation. Early in cure, this conductivity

increases steadily as the viscosity decreases due to the temperature rise. As the cure proceeds, the conductivity reaches a maximum, then begins to decrease. This indicates that the increase in viscosity due to crosslinking is beginning to dominate the intrinsic temperature dependence of the viscosity. The results demonstrate the suitability of the microdi-electrometer for obtaining process control data during cure.

3.2 Cure Control Experiments

The on-chip temperature sensor provides an interesting capability

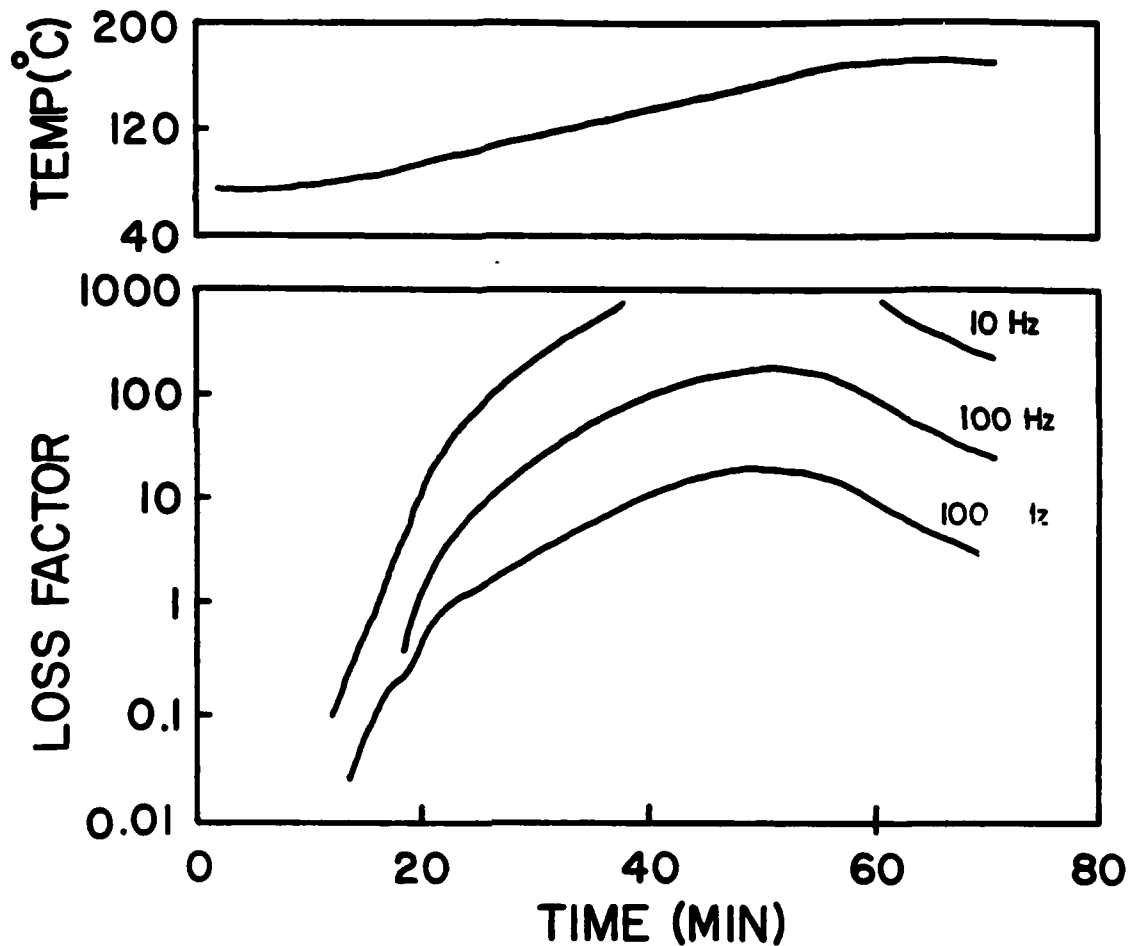


Fig. 5 Loss factor and temperature versus time for ramped prepreg cure.

for closed-loop control. As a test of this capability, the following experiment was performed (11). A pair of Microdiectrometer chips was bonded within a single 16-pin ceramic DIP package. A photomicrograph is shown in Figure 6. One of the chips was used as a heater/controller, with 3 Watts of 20 kHz AC power dissipation in the on-chip transistors being used to heat the chip, the ceramic substrate, and the other chip bonded to the substrate. A switching controller used the temperature signal derived from the diode in the heater/controller chip to

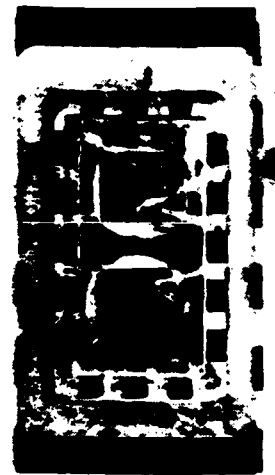


Fig. 6 "Microclave" showing dielectric sensor, top, and heater/controller, bottom.

achieve regulation of better than 1°C . The second microdielectrometer chip was used as a cure monitor, with its on-chip temperature sensor making an independent measurement of the actual temperature at the cure-monitoring electrodes. Thus the entire cure-monitoring test station, including the function of the oven, was merged into a single integrated circuit package, which we have called the "Microclave". The resin used for this experiment was DGEBA cured with MPDA. Figures 7 and 8 show the dielectric permittivity and loss factor data obtained from this experiment. Note that all of the features seen in Figure 2 are also observed in this experiment. Such an assembly would make a particularly compact test station for quality assurance inspection of resins.

4. CONCLUSIONS

In viewing the results presented above, it is important to keep several issues in mind. First, the frequency dependence of ϵ'' is a particularly useful experimental quantity to monitor. From it, one can be certain whether one is observing conductivity or dipole orientation effects. Second, early in cure, conductivity as revealed in the loss factor correlates with viscosity, and can potentially be used for cure control (for example, to locate the viscosity minimum in prepreg). Third, par-

allel plate techniques of measurement are better suited for loss tangent measurement than for loss factor measurement, because the plate spacing may not be either accurately known, or may not be constant in typical cure cycles. When the permittivity is itself changing with cure, as happens with conductivity-induced artifacts as in Figure 2, then the behavior of the loss tangent is complex, and less easily interpretable. Fourth, the fixed electrode geometry of the Microdielectrometer provides for direct observation of loss factor, with the effects of temperature and pressure variation cancelled by differential measurement techniques. Finally, the Microdielectrometer technology provides for easy incorporation of moderate accuracy semiconductor diode temperature sensors into a combined dielectric/temperature probe. The probe is implantable, makes a highly localized measurement of both dielectric properties and temperature, and provides both kinds of signals for potential cure-control applications.

5. ACKNOWLEDGEMENTS

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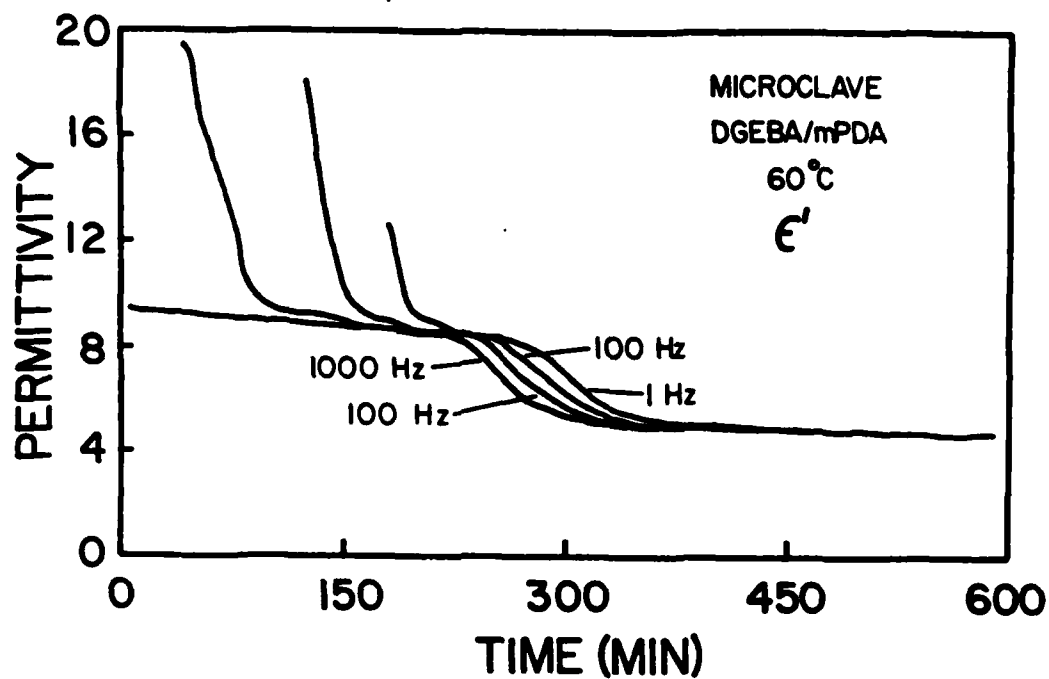


Fig. 7 ϵ' versus time for DGEBA/MPDA cured in "Microclave"

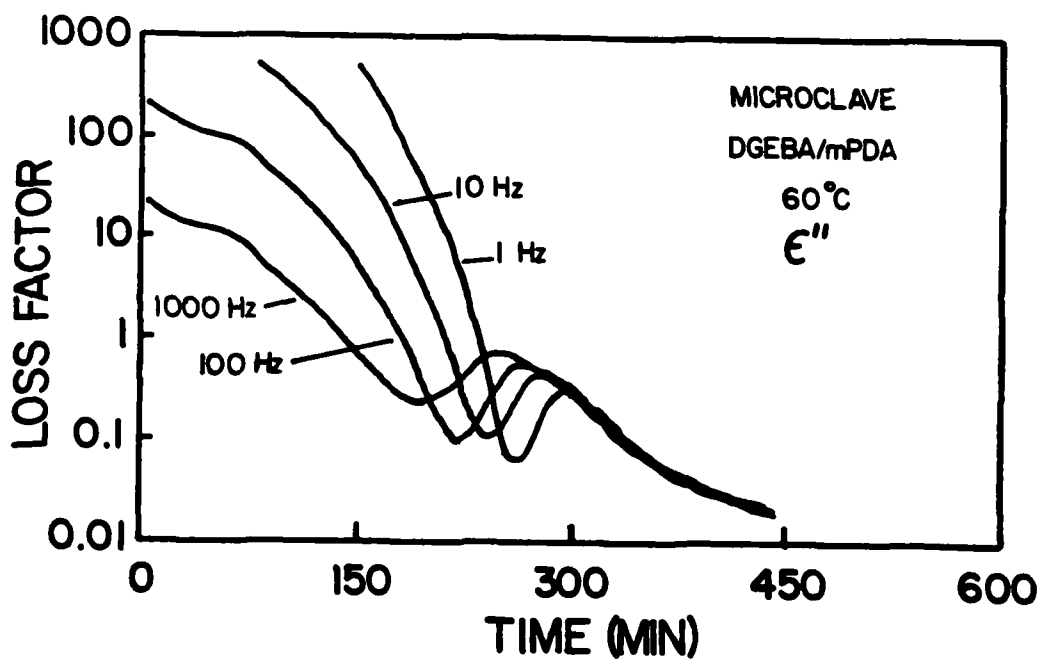


Fig. 8 ϵ'' versus time for DGEBA/MPDA cured in "Microclave"

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